IXYS

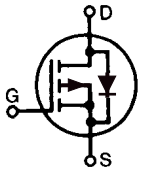
Standard Power MOSFET

IXTH 16P20

V_{DSS} = -200 V
I_{D25} = -16 A
$R_{DS(on)}$ = 0.16 Ω

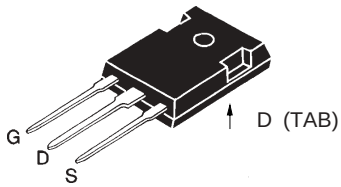
P-Channel Enhancement Mode
Avalanche Rated

Preliminary Data Sheet



Symbol	Test Conditions	Maximum Ratings	
V_{DSS}	T_J = 25°C to 150°C	-200	V
V_{DGR}	T_J = 25°C to 150°C; R_{GS} = 1 MΩ	-200	V
V_{GS}	Continuous	±20	V
V_{GSM}	Transient	±30	V
I_{D25}	T_C = 25°C	-16	A
I_{DM}	T_C = 25°C, pulse width limited by T_J	-64	A
I_{AR}	T_C = 25°C	-16	A
E_{AR}	T_C = 25°C	30	mJ
P_D	T_C = 25°C	300	W
T_J		-55 ... +150	°C
T_{JM}		150	°C
T_{stg}		-55 ... +150	°C
T_L	Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s	300	°C
M_d	Mounting torque	1.13/10	Nm/lb.in.
Weight		6	g

TO-247 AD



G = Gate, D = Drain,
S = Source, TAB = Drain

Features

- International standard package JEDEC TO-247 AD
- Low $R_{DS\ (on)}$ HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Low package inductance (<5 nH) - easy to drive and to protect

Symbol	Test Conditions	Characteristic Values (T_J = 25°C, unless otherwise specified) min.	typ.	max.	
V_{DSS}	V_{GS} = 0 V, I_D = -250 μA	-200			V
$V_{GS(th)}$	$V_{DS} = V_{GS}$, I_D = -250 μA	-3.0		-5.0	V
I_{GSS}	V_{GS} = ±20 V_{DC}, V_{DS} = 0			±100	nA
I_{DSS}	V_{DS} = 0.8 • V_{DSS}, V_{GS} = 0 V; T_J = 25°C			-25	μA
				-1	mA
	T_J = 125°C				
$R_{DS(on)}$	V_{GS} = -10 V, I_D = 0.5 • I_{D25}			0.16	Ω

Applications

- High side switching
- Push-pull amplifiers
- DC choppers
- Automatic test equipment

Advantages

- Easy to mount with 1 screw (isolated mounting screw hole)
- Space savings
- High power density

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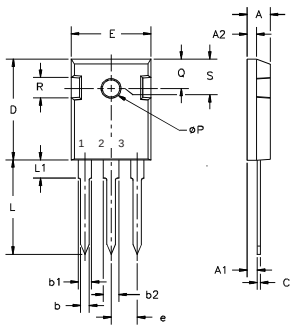
Symbol	Test Conditions (T_J = 25°C, unless otherwise specified)	Characteristic Values min.	typ.	max.	
g_{fs}	V_{DS} = -10 V; I_D = I_{D25}, pulse test	6	10		S
C_{iss}	V_{GS} = 0 V, V_{DS} = -25 V, f = 1 MHz		2800		pF
C_{oss}			550		pF
C_{rss}			240		pF
$t_{d(on)}$	V_{GS} = -10 V, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25} R_G = 4.7 Ω (External)		33		ns
t_r			26		ns
$t_{d(off)}$			65		ns
t_f			25		ns
$Q_{g(on)}$	V_{GS} = -10 V, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}		95		nC
Q_{gs}			27		nC
Q_{gd}			40		nC
R_{thJC}				0.42	K/W
R_{thCS}			0.25		K/W

TO-247 AD Outline



Terminals: 1 - Gate 2 - Drain
3 - Source Tab - Drain

Dim.	Millimeter Min.	Max.	Inches Min.	Max.
A	4.7	5.3	.185	.209
A_1	2.2	2.54	.087	.102
A_2	2.2	2.6	.059	.098
b	1.0	1.4	.040	.055
b_1	1.65	2.13	.065	.084
b_2	2.87	3.12	.113	.123
C	.4	.8	.016	.031
D	20.80	21.46	.819	.845
E	15.75	16.26	.610	.640
e	5.20	5.72	0.205	0.225
L	19.81	20.32	.780	.800
L1		4.50		.177
∅P	3.55	3.65	.140	.144
Q	5.89	6.40	0.232	0.252
R	4.32	5.49	.170	.216
S	6.15	BSC	242	BSC

Source-Drain Diode

Symbol	Test Conditions (T_J = 25°C, unless otherwise specified)	Characteristic Values min.	typ.	max.	
I_S	V_{GS} = 0			-16	A
I_{SM}	Repetitive; pulse width limited by T_{JM}			-64	A
V_{SD}	I_F = I_S, V_{GS} = 0 V, Pulse test, t ≤ 300 µs, duty cycle d ≤ 2 %			-3	V
t_{rr}	I_F = I_S, di/dt = 100 A/µs, V_R = -50 V		250		ns

IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,881,106 5,017,508 5,049,961 5,187,117 5,486,715 6,306,728B1 6,259,123B1 6,306,728B1 4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025 6,404,065B1 6,162,665 6,534,343 6,583,505

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